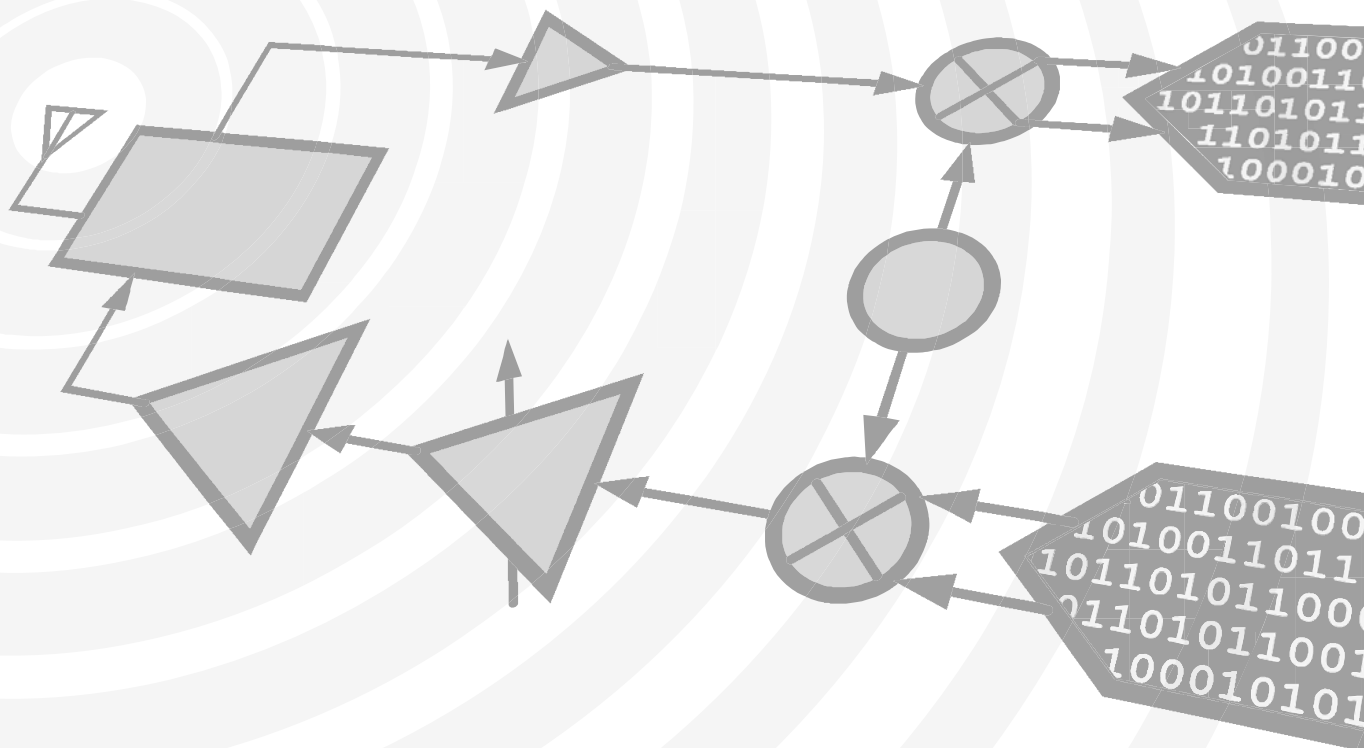




NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



THIS PAGE INTENTIONALLY LEFT BLANK



MICROWAVE CORPORATION

v03.0308



HMC320MS8G / 320MS8GE

**GaAs MMIC LOW NOISE
AMPLIFIER , 5 - 6 GHz**

Typical Applications

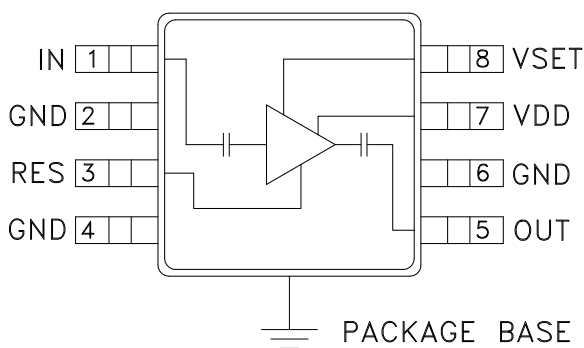
The HMC320MS8G(E) is ideal for:

- UNII
- HiperLAN

Features

- Selectable Functionality:
LNA, Driver, or LO Buffer Amp
- Adjustable Input IP3 Up to +10 dBm
- +3V Operation
- Ultra Small 8 Lead MSOP: 14.8 x 14.8 x 1 mm

Functional Diagram



General Description

The HMC320MS8G & HMC320MS8GE are low cost C-band fixed gain Low Noise Amplifiers (LNA). The HMC320MS8G & HMC320MS8GE operate using a single positive supply that can be set between +3V and +5V. With +3V bias, the LNA provides a noise figure of 2.5 dB, 1 dB gain and better than 10 dB return loss across the UNII band. The HMC320MS8G & HMC320MS8GE also feature an adaptive biasing that allows the user to select the optimal P1dB performance for their system using an external set resistor on the "RES" pin. P1dB performance can be set between a range of +1 dBm to +13 dBm. The low cost LNA uses an 8-leaded MSOP ground base surface mount plastic package, which occupies less than 14.8 mm².

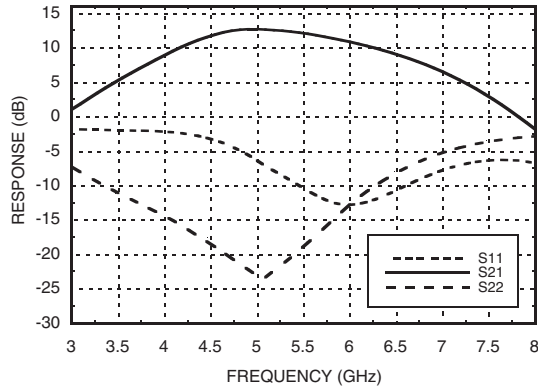
Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{dd} = +3\text{V}$

Parameter	Low Power* (VSET = 0V, Idd = 7 mA)			Medium Power* (VSET = 3V, Idd = 25 mA)			High Power* (VSET = 3V, Idd = 40 mA)			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range	5 - 6			5 - 6			5 - 6			GHz
Gain	8	10	16	8	12	16	9	13	16	dB
Gain Variation over Temperature		0.025	0.035		0.025	0.035		0.025	0.035	dB/°C
Gain Flatness		±0.5			±1.0			±1.5		dB
Noise Figure		2.7	3.8		2.5	3.8		2.6	3.8	dB
Input Return Loss	4	10		4	10		4	10		dB
Output Return Loss	7	13		10	18		10	20		dB
Output Power for 1 dB Compression (P1dB)	-4	-1		6	9		9	12		dBm
Input Third Order Intercept Point (IIP3)	-3	1		4	8		6	10		dBm
Supply Current (Idd)		7			25			40		mA

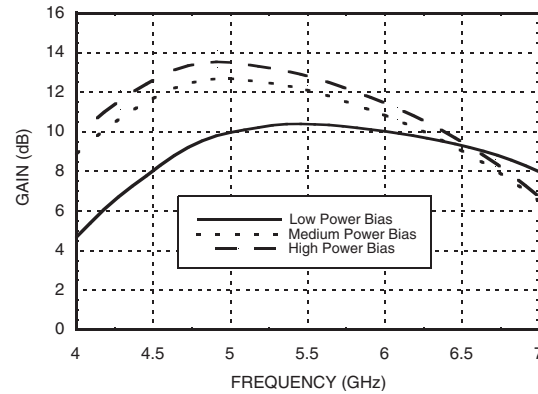
* R_{BIAS} resistor value sets current. See adaptive biasing application note.

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order On-line at www.hittite.com

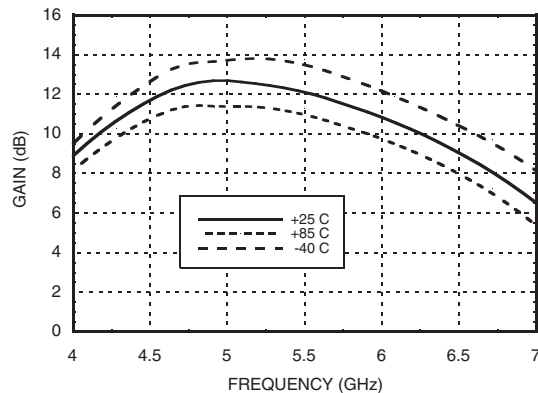
Broadband Gain & Return Loss Medium Power Bias



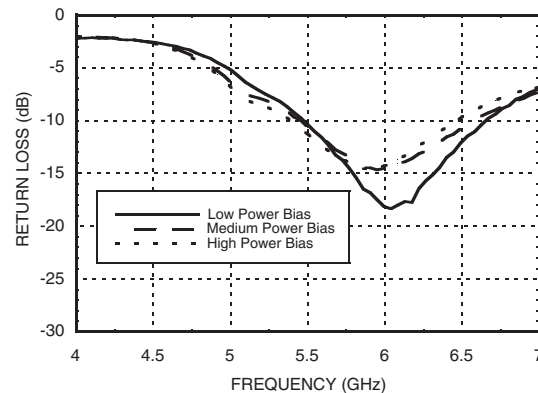
Gain @ Three Bias Conditions



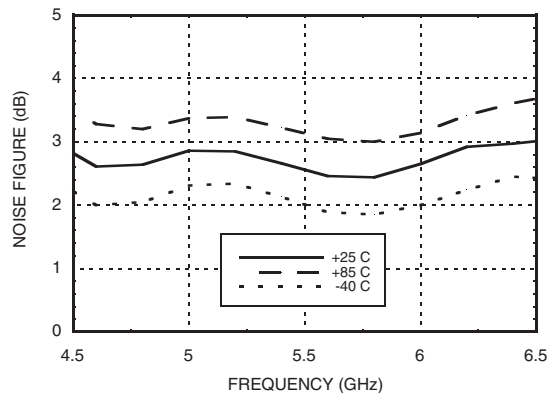
Gain vs. Temperature Medium Power Bias



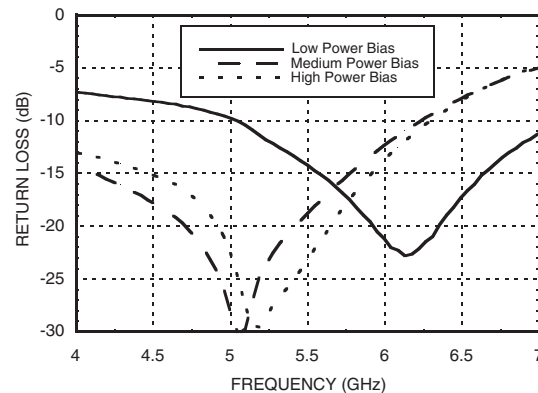
Input Return Loss @ Three Bias Conditions



Noise Figure vs. Temperature Medium Power Bias

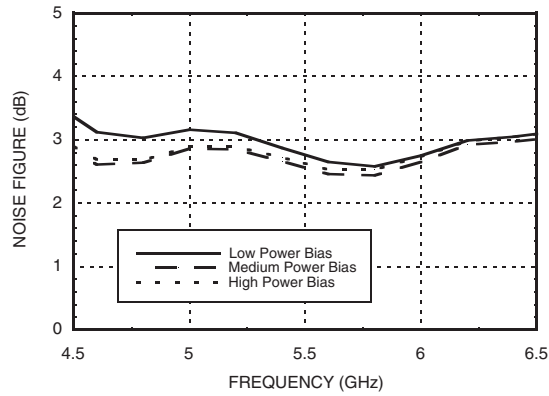


Output Return Loss @ Three Bias Conditions

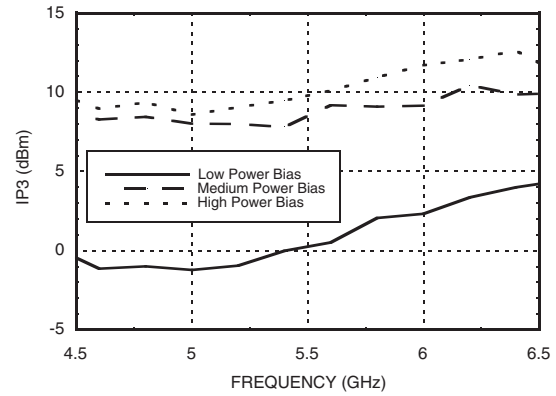


Noise Figure

@ Three Bias Conditions

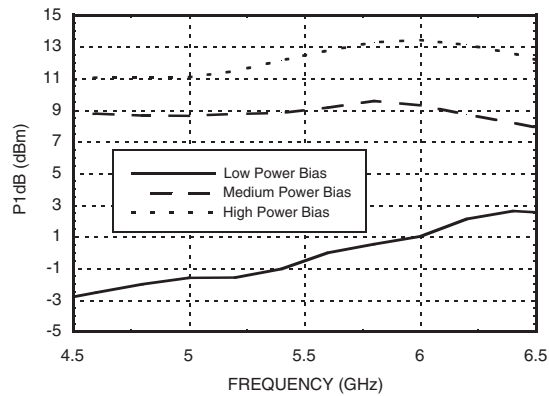


Input IP3 @ Three Bias Conditions



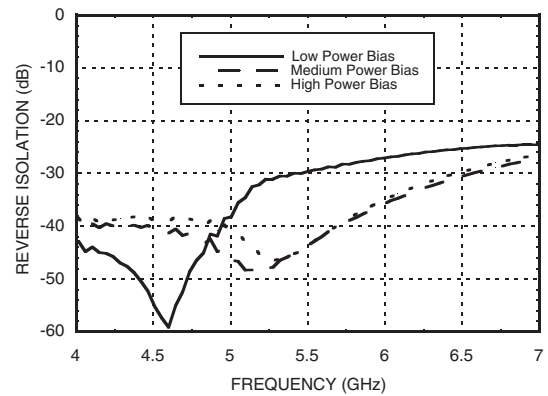
Output 1dB Compression

@ Three Bias Conditions



Reverse Isolation

@ Three Bias Conditions



Adaptive Biasing

Optimizing P1dB Performance

The bias level may be changed to adjust the P1dB and return loss performance. The table below contains the HMC-320MS8G RF performance as a function of various VSET and RBIAS settings. It will be necessary for the VSET voltage source to provide 100uA of current to the amplifier. The Idd and Vdd quiescent performance will not change as a function of changing the VSET voltage.

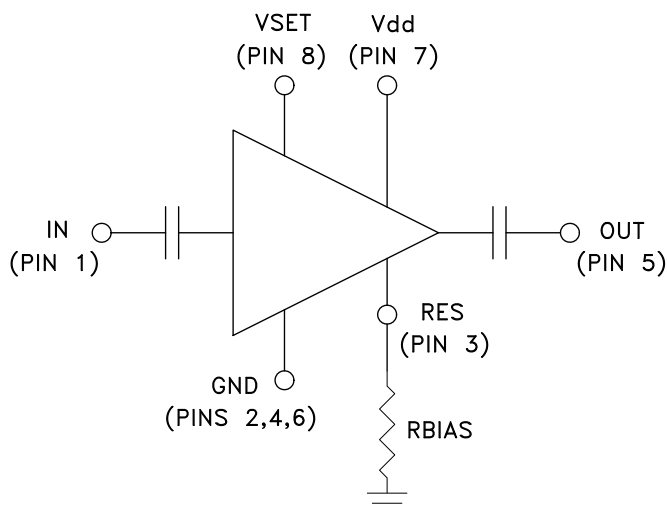
RF Performance at 5.8 GHz (Vdd = +3V)

VSET (VDC)	RBIAS Resistor Between Pin 3 and GND (Ohms)	Idd (mA)	Output P1dB (dBm)	Output Return Loss (dB)
0	174	7	1.0	16.0
3	22	25	9.0	12.0
3	7	40	13.0	15.0
3	GND (No Resistor)	60	14.0	15.0

Applying the adaptive biasing

A dynamically controlled bias can be implemented with this design. A typical application will include sensing an RF signal level and then adjusting the VSET. The bias adjustment can be accomplished by either analog or digital means, after the RF signal has been detected and translated to a DC voltage using external power detection circuitry.

Schematic





MICROWAVE CORPORATION v03.0308



HMC320MS8G / 320MS8GE

GaAs MMIC LOW NOISE
AMPLIFIER, 5 - 6 GHz

Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+7.0 Vdc
Control Voltage Range (VSET)	0 to Vdd
RF Input Power (RFIN)(Vdd = +3.0 Vdc)	+5 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 2.98 mW/°C above 85 °C)	0.194 W
Thermal Resistance (channel to ground paddle)	336 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Truth Table

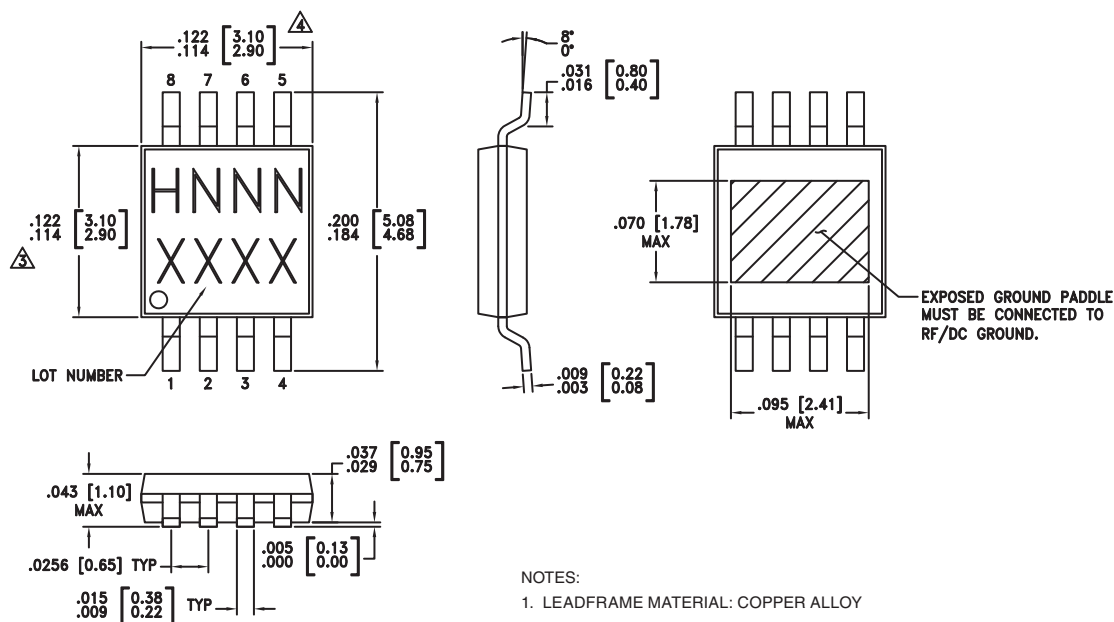
VSET	Operating Current Idd	Operating State	Resistor Rbias
0V	7 mA	Low Power	174 Ohm
3V	25 mA	Medium Power	22 Ohm
3V	40 mA	High Power	7 Ohm

Set external bias resistor (RBIAS) to achieve desired operating current, $0 < R_{BIAS} < 200 \text{ Ohm}$.



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

- LEADFRAME MATERIAL: COPPER ALLOY
- DIMENSIONS ARE IN INCHES [MILLIMETERS]
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
- DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC320MS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H320 XXXX
HMC320MS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H320 XXXX

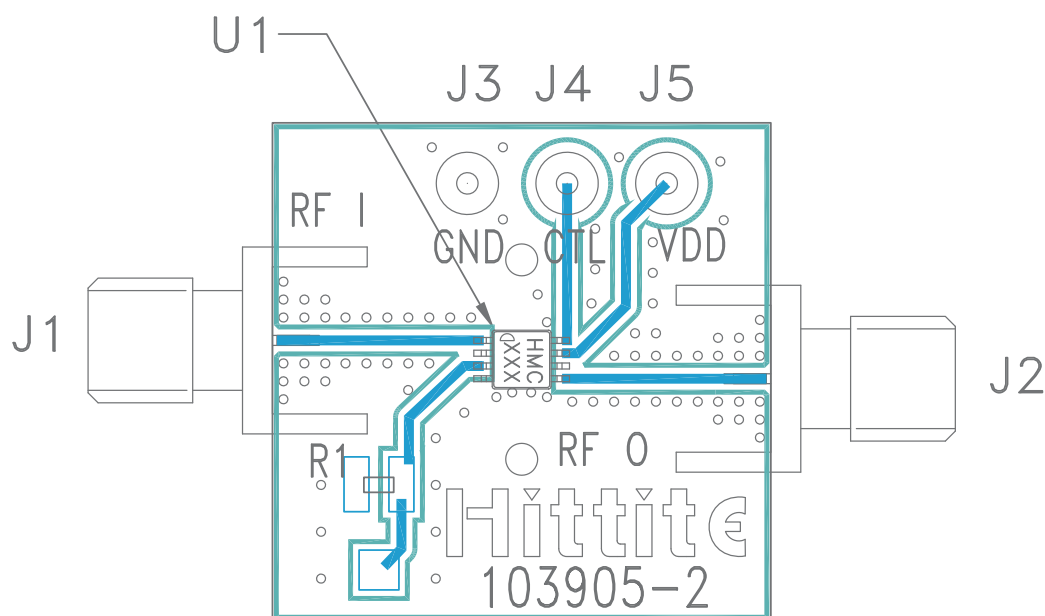
[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order On-line at www.hittite.com

Evaluation PCB



List of Materials for Evaluation PCB 103907 ^[1]

Item	Description
J1, J2	PCB Mount SMA Connector
J3, J4, J5	DC Pins
R1	22 Ohm Resistor, 0603 Pkg.
U1	HMC320MS8G / HMC320MS8GE Amplifier
PCB [2]	103905 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.